

DATA SHEET

TZA3041AHL; TZA3041BHL; TZA3041U Gigabit Ethernet/Fibre Channel laser drivers

Objective specification
File under Integrated Circuits, IC19

1998 Aug 24

Gigabit Ethernet/Fibre Channel laser drivers

TZA3041AHL; TZA3041BHL; TZA3041U

FEATURES

- 1.2 Gbits/s data input, both Current-Mode Logic (CML) and Positive Emitter Coupled Logic (PECL) compatible; maximum 800 mV (peak-to-peak value)
- Adaptive laser output control, stabilizing optical ONE and ZERO levels
- Optional external (non-adaptive) control of laser modulation and biasing currents
- Automatic Laser Shut-down (ALS)
- Few external components required
- Rise and fall times typically 120 ps
- Jitter <50 mUI (peak-to-peak value)
- RF output current sinking capability of 60 mA
- Bias current sinking capability of 90 mA
- Power dissipation typically 475 mW
- Low cost LQFP32 plastic package
- Single 5 V power supply.

TZA3041AHL

- Laser alarm output for signalling extremely low and high bias current conditions.

TZA3041BHL

- Loop mode for testing 1.2 Gbits/s optical interfaces; CML and PECL compatible.

TZA3041U

- Naked die version with combined bias alarm and loop mode functionality.

APPLICATIONS

- Gigabit Ethernet/Fibre Channel optical transmission systems
- Gigabit Ethernet/Fibre Channel optical laser modules.

DESCRIPTION

The TZA3041AHL, TZA3041BHL and TZA3041U are fully integrated laser drivers for Gigabit Ethernet/Fibre Channel (1.2 Gbits/s) systems, incorporating the RF path between the data multiplexer and the laser diode. Since the bias and modulation control circuits are integrated on the IC, the external component count is low (only decoupling capacitors and adjustment resistors are required).

The TZA3041AHL features an alarm function for signalling extreme bias current conditions. The alarm low and high threshold levels can be adjusted to suit the application using only a resistor. An additional RF data input is provided with the TZA3041BHL to facilitate remote (loop mode) system testing.

The TZA3041U is a naked die version for use in compact laser module designs. The die contains 40 pads and features the combined functionality of the TZA3041AHL and TZA3041BHL.

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | |
|-------------|---------|--|----------|
| | NAME | DESCRIPTION | VERSION |
| TZA3041AHL | LQFP32 | plastic low profile quad flat package; 32 leads; body 5 × 5 × 1.4 mm | SOT401-1 |
| TZA3041BHL | | | |
| TZA3041U | – | naked die; 2000 × 2000 × 380 μm | – |

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BLOCK DIAGRAMS

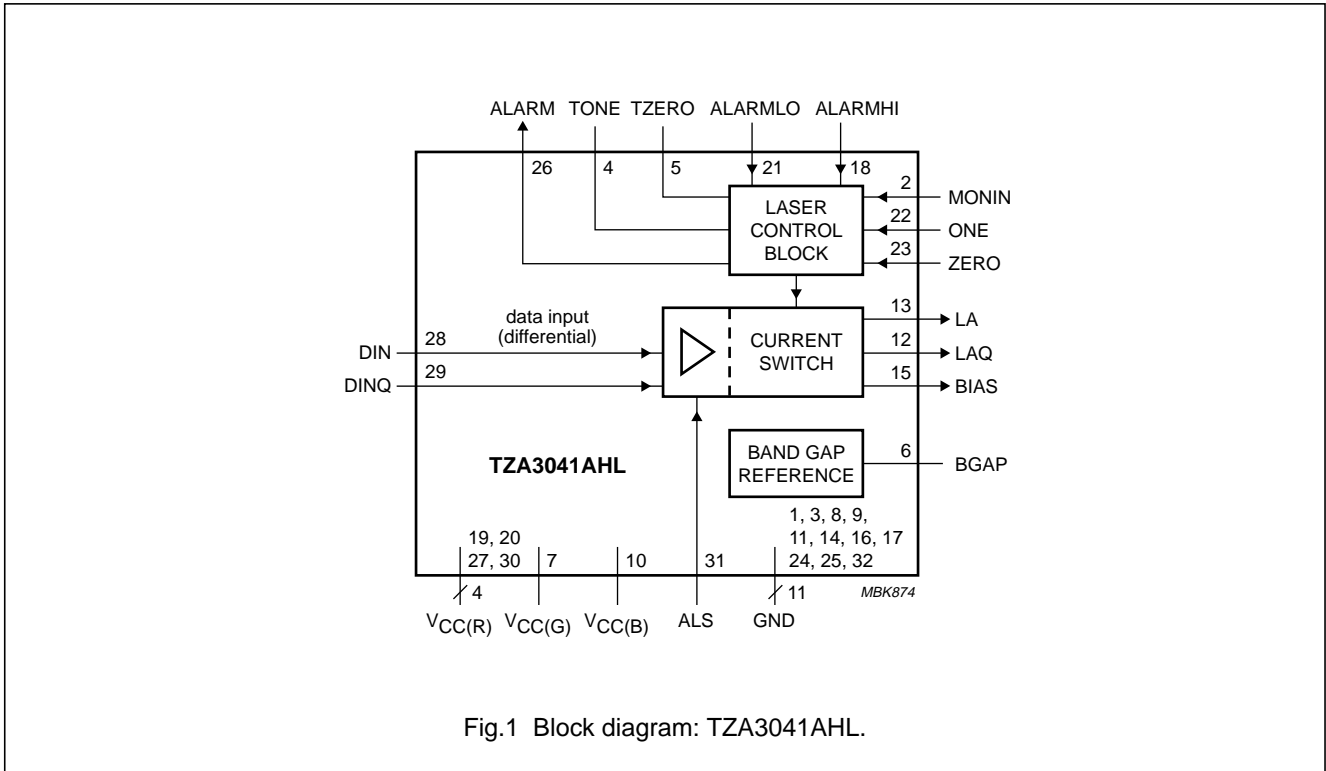


Fig.1 Block diagram: TZA3041AHL.

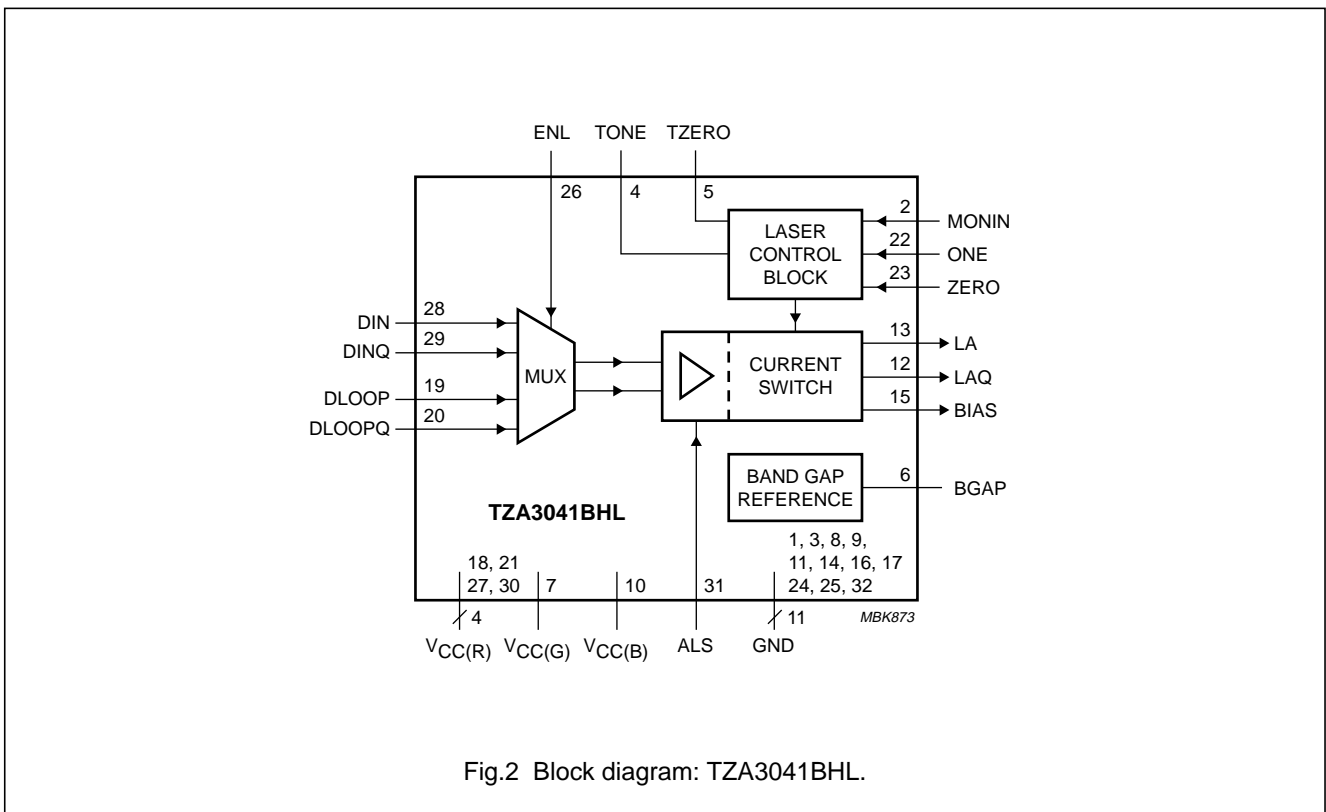


Fig.2 Block diagram: TZA3041BHL.

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PINNING

TZA3041AHL

| SYMBOL | PIN | DESCRIPTION |
|--------------------|-----|--|
| GND | 1 | ground |
| MONIN | 2 | monitor photodiode current input |
| GND | 3 | ground |
| TONE | 4 | connection for external capacitor used to set optical ONE control loop time constant (optional) |
| TZERO | 5 | connection for external capacitor used to set optical ZERO control loop time constant (optional) |
| BGAP | 6 | connection for external band gap decoupling capacitor |
| V _{CC(G)} | 7 | supply voltage; note 1 |
| GND | 8 | ground |
| GND | 9 | ground |
| V _{CC(B)} | 10 | supply voltage; note 1 |
| GND | 11 | ground |
| LAQ | 12 | inverted laser modulation output |
| LA | 13 | laser modulation output |
| GND | 14 | ground |
| BIAS | 15 | laser bias current output |
| GND | 16 | ground |
| GND | 17 | ground |
| ALARMHI | 18 | maximum bias current alarm reference level input |
| V _{CC(R)} | 19 | supply voltage; note 1 |
| V _{CC(R)} | 20 | supply voltage; note 1 |
| ALARMLO | 21 | minimum bias current alarm reference level input |
| ONE | 22 | optical ONE reference level input |
| ZERO | 23 | optical ZERO reference level input |
| GND | 24 | ground |
| GND | 25 | ground |
| ALARM | 26 | alarm output |
| V _{CC(R)} | 27 | supply voltage; note 1 |
| DIN | 28 | data input |
| DINQ | 29 | inverted data input |
| V _{CC(R)} | 30 | supply voltage; note 1 |
| ALS | 31 | automatic laser shut-down input |
| GND | 32 | ground |

TZA3041BHL

| SYMBOL | PIN | DESCRIPTION |
|--------------------|-----|--|
| GND | 1 | ground |
| MONIN | 2 | monitor photodiode current input |
| GND | 3 | ground |
| TONE | 4 | connection for external capacitor used to set optical ONE control loop time constant (optional) |
| TZERO | 5 | connection for external capacitor used to set optical ZERO control loop time constant (optional) |
| BGAP | 6 | connection for external band gap decoupling capacitor |
| V _{CC(G)} | 7 | supply voltage; note 1 |
| GND | 8 | ground |
| GND | 9 | ground |
| V _{CC(B)} | 10 | supply voltage; note 1 |
| GND | 11 | ground |
| LAQ | 12 | inverted laser modulation output |
| LA | 13 | laser modulation output |
| GND | 14 | ground |
| BIAS | 15 | laser bias current output |
| GND | 16 | ground |
| GND | 17 | ground |
| V _{CC(R)} | 18 | supply voltage; note 1 |
| DLOOP | 19 | loop mode data input |
| DLOOPQ | 20 | loop mode inverted data input |
| V _{CC(R)} | 21 | supply voltage; note 1 |
| ONE | 22 | optical ONE reference level input |
| ZERO | 23 | optical ZERO reference level input |
| GND | 24 | ground |
| GND | 25 | ground |
| ENL | 26 | loop mode enable input |
| V _{CC(R)} | 27 | supply voltage; note 1 |
| DIN | 28 | data input |
| DINQ | 29 | inverted data input |
| V _{CC(R)} | 30 | supply voltage; note 1 |
| ALS | 31 | automatic laser shutdown input |
| GND | 32 | ground |

Note to Tables TZA3041AHL and TZA3041BHL

1. See Section "Power supply connections".

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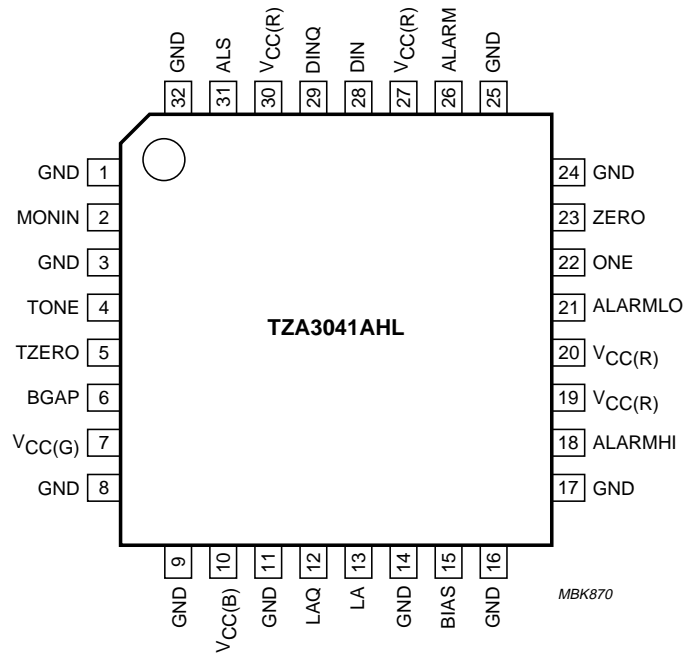


Fig.3 Pin configuration: TZA3041AHL.

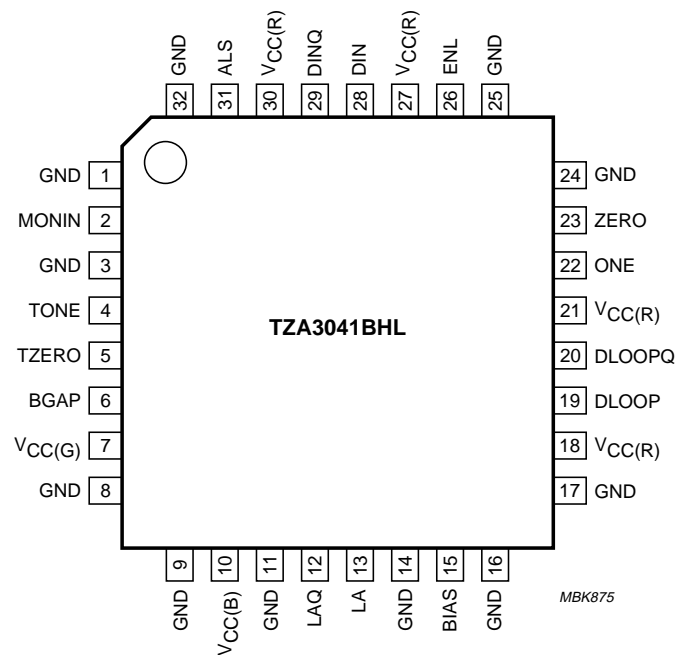


Fig.4 Pin configuration: TZA3041BHL.

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PAD CONFIGURATION

TZA3041U (naked die)

| SYMBOL | PAD | DESCRIPTION | COORDINATES ⁽¹⁾ | |
|--------------------|-----|---|----------------------------|------|
| | | | x | y |
| GND | 1 | ground | -664 | -910 |
| MONIN | 2 | monitor photodiode current input | -524 | -910 |
| GND | 3 | ground | -367 | -910 |
| IGM | 4 | not used (leave unbonded) | -227 | -910 |
| TONE | 5 | connection for external capacitor to set optical ONE control loop time constant (optional) | -70 | -910 |
| TZERO | 6 | connection for external capacitor to set optical ZERO control loop time constant (optional) | +87 | -910 |
| BGAP | 7 | connection for external band gap decoupling capacitor | +244 | -910 |
| V _{CC(G)} | 8 | supply voltage | +384 | -910 |
| V _{CC(G)} | 9 | supply voltage | +524 | -910 |
| GND | 10 | ground | +664 | -910 |
| GND | 11 | ground | +910 | -630 |
| V _{CC(B)} | 12 | supply voltage | +910 | -490 |
| V _{CC(B)} | 13 | supply voltage | +910 | -350 |
| GND | 14 | ground | +910 | -210 |
| LAQ | 15 | inverted laser modulation output | +910 | -70 |
| LA | 16 | laser modulation output | +910 | +70 |
| GND | 17 | ground | +910 | +210 |
| BIAS | 18 | laser bias current output | +910 | +350 |
| GND | 19 | ground | +910 | +490 |
| GND | 20 | ground | +910 | +630 |
| GND | 21 | ground | +681 | +910 |
| ALARMHI | 22 | maximum bias current alarm reference level input | +541 | +910 |
| V _{CC(R)} | 23 | supply voltage | +384 | +910 |
| DLOOP | 24 | loop mode data input | +227 | +910 |
| DLOOPQ | 25 | loop mode inverted data input | +87 | +910 |
| V _{CC(R)} | 26 | supply voltage | -70 | +910 |
| ALARMLO | 27 | minimum bias current reference level input | -210 | +910 |
| ONE | 28 | optical ONE reference level input | -367 | +910 |
| ZERO | 29 | optical ZERO reference level input | -524 | +910 |
| GND | 30 | ground | -681 | +910 |
| GND | 31 | ground | -910 | +681 |
| ALARM | 32 | alarm output | -910 | +541 |
| ENL | 33 | loop mode enable input | -910 | +384 |
| V _{CC(R)} | 34 | supply voltage | -910 | +227 |
| DIN | 35 | data input | -910 | +70 |

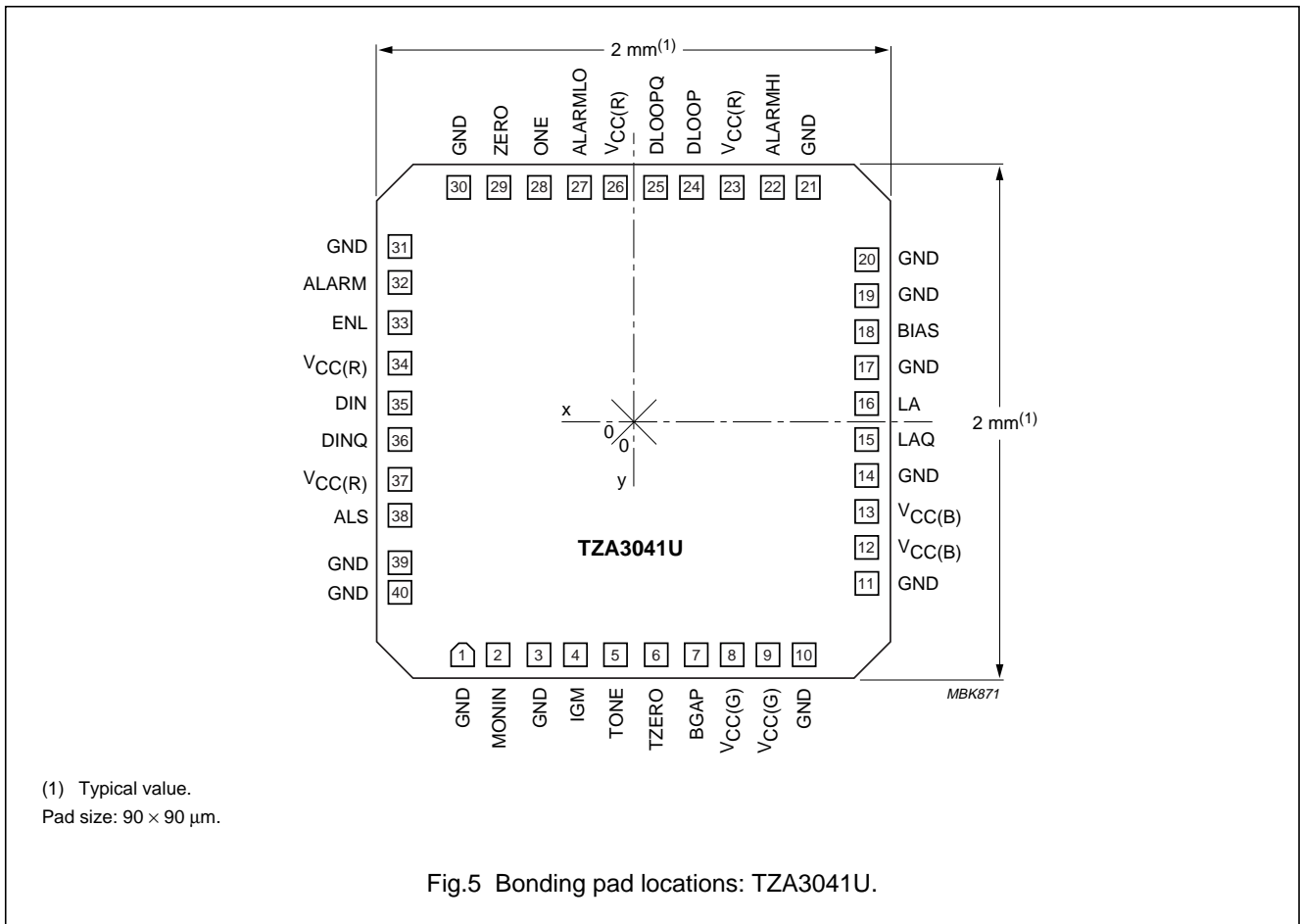
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| SYMBOL | PAD | DESCRIPTION | COORDINATES ⁽¹⁾ | |
|--------------------|-----|---------------------------------|----------------------------|------|
| | | | x | y |
| DINQ | 36 | inverted data input | -910 | -70 |
| V _{CC(R)} | 37 | supply voltage | -910 | -227 |
| ALS | 38 | automatic laser shut-down input | -910 | -367 |
| GND | 39 | ground | -910 | -551 |
| GND | 40 | ground | -910 | -664 |

Note

- Coordinates represent the position of the centre of the pad, in µm with respect to the centre of the die.



FUNCTIONAL DESCRIPTION

The TZA3041AHL, TZA3041BHL and TZA3041U laser drivers accept a 1.2 Gbits/s input data stream (CML or PECL compatible) and generate an output signal with sufficient current to drive a solid state laser. They also contain control circuitry for stabilizing the laser optical power levels representing logic 1 and logic 0.

The input buffers present a high impedance to the data stream on the DIN and DINQ differential inputs. The input signal can be CML, approximately 200 mV (peak-to-peak value) below the supply voltage or PECL up to 800 mV (peak-to-peak value) compatible. The input can be configured to accept CML signals by connecting external 50 Ω pull-up resistors to V_{CC(R)}. If PECL compatibility is required, the usual Thevenin termination can be applied.

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For ECL signals (negative to ground), the inputs should be AC-coupled to the signal source.

The differential amplifier contains a preamplifier and a main amplifier. The main amplifier is designed to handle the large peak currents required at the output laser driving stage and is insensitive to supply voltage variations. The output signal from the main amplifier drives a current switch which supplies a maximum modulation current of 60 mA through outputs LA and LAQ. The BIAS pin delivers a bias current of up to 90 mA DC for adjusting the laser output to a level above its light emitting threshold.

Automatic laser control

A laser with a Monitor PhotoDiode (MPD) is required for the laser control circuit. The MPD current, which is proportional to the laser emission, is fed into pin MONIN; the current range is 100 to 1000 μA (peak-to-peak value). The input buffer is optimized to cope with MPD capacitances up to 50 pF. To prevent the input buffer breaking into oscillation with a low capacitance MPD, it is advisable to increase the capacitance to at least the minimum specified value (see Chapter "Characteristics"), by connecting extra capacitance to the MONIN pin.

DC reference currents are applied to pins ZERO and ONE to set the MPD reference levels for laser LOW and laser HIGH. A resistor between $V_{CC(R)}$ and the pin is sufficient; the voltage on the ZERO and ONE pins is held constant at a level 1.5 V below $V_{CC(R)}$. The reference current applied to pin ZERO is multiplied by 4, the reference current flowing into pin ONE is multiplied internally by 16. The above mentioned factors are first estimations and will be finalized after full product characterization.

The reference current and resistor for the optical ONE regulation loop (modulation current control) can be calculated using the following formulae:

$$I_{\text{ONE}} = \frac{1}{16} \cdot I_{\text{MPD(ONE)}} \quad [\text{A}] \quad (1)$$

$$R_{\text{ONE}} = \frac{1.5}{I_{\text{ONE}}} = \frac{24}{I_{\text{MPD(ONE)}}} \quad [\Omega] \quad (2)$$

The reference current and resistor for the optical ZERO regulation loop (bias current control) can be calculated using the following formulae:

$$I_{\text{ZERO}} = \frac{1}{4} \cdot I_{\text{MPD(ZERO)}} \quad [\text{A}] \quad (3)$$

$$R_{\text{ZERO}} = \frac{1.5}{I_{\text{ZERO}}} = \frac{6}{I_{\text{MPD(ZERO)}}} \quad [\Omega] \quad (4)$$

In these formulae, $I_{\text{MPD(ONE)}}$ and $I_{\text{MPD(ZERO)}}$ represent monitor photodiode current during an optical ONE and an optical ZERO, respectively.

Example: A laser is operating at optical output power levels of 0.3 mW for laser HIGH and 0.03 mW for laser LOW (extinction ratio of 10 dB). Suppose the corresponding MPD currents for this type of laser are 260 μA and 30 μA respectively. In this case, a reference current of $\frac{260 \mu\text{A}}{16} = 16.25 \mu\text{A}$ should flow into pin ONE.

This can be set using a current source or simply by connecting a resistor of the appropriate value. The resistor can be connected between $V_{CC(R)}$ and pin ONE. In this example the resistor would be

$$R_{\text{ONE}} = \frac{1.5 \text{ V}}{16.25 \mu\text{A}} = 92.3 \text{ k}\Omega \quad (\text{the voltage on pin ONE is held constant at 1.5 V below } V_{CC(R)}).$$

The reference current at pin ZERO in this example should be $\frac{30 \mu\text{A}}{4} = 7.5 \mu\text{A}$. Again this current should flow into pin ZERO and can be set using a resistor

$$R_{\text{ZERO}} = \frac{1.5 \text{ V}}{7.5 \mu\text{A}} = 200 \text{ k}\Omega \quad (\text{the voltage on pin ZERO is held constant at 1.5 V below } V_{CC(R)}).$$

It should be noted that the MPD current is stabilized, rather than the actual laser optical output power. Deviations between optical output power and MPD current, known as 'tracking errors', cannot be corrected for.

Manual laser override

The automatic laser control function can be overridden by connecting voltage sources to TZERO and TONE to take direct control of, respectively, the bias current source and the modulation current source. The control voltages should be in the range 1.5 to 3.5 V to sweep the modulation current through the range 1 to 60 mA and the bias current through the range 1 to 90 mA. These current ranges are guaranteed. Depending on temperature and manufacturing process spread, current values higher than the specified ranges can be achieved. However, bias and modulation currents in excess of the specified range are not supported and should be avoided.

Automatic laser shut-down

The laser modulation and bias currents can be rapidly switched off by means of the active HIGH ALS input (CMOS). This function allows the circuit to be shut-down in the event of an optical system malfunction.

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A 25 kΩ pull-down resistor defaults the ALS input to the non active state.

Bias alarm (TZA3041AHL only)

The bias current alarm circuit detects and flags whenever the bias current falls outside a predefined range. This feature can detect excessive aging and laser malfunctioning. The maximum permitted bias current should be applied to ALARMHI with an attenuation ratio of 1500, the minimum to ALARMLO with an attenuation ratio of 300.

Like the reference currents for the laser current regulation loops, the alarm reference currents can be set using external resistors between V_{CC(R)} and pins ALARMHI and ALARMLO. Resistor values can be calculated using the following formulae:

$$R_{ALARMHI} = \frac{1.5 \cdot 1500}{I_{BIAS_{MAX}}} \quad [\Omega] \quad (5)$$

$$R_{ALARMLO} = \frac{1.5 \cdot 300}{I_{BIAS_{MIN}}} \quad [\Omega] \quad (6)$$

Example: The following reference currents would be required to limit the bias current range to between 6 and 90 mA:

$$I_{ALARMLO} = \frac{6 \text{ mA}}{300} = 20 \mu\text{A}$$

$$I_{ALARMHI} = \frac{90 \text{ mA}}{1500} = 60 \mu\text{A}$$

The corresponding resistor values would be:

$$R_{ALARMHI} = \frac{1.5 \text{ V} \cdot 1500}{90 \text{ mA}} = 25 \text{ k}\Omega$$

$$R_{ALARMLO} = \frac{1.5 \text{ V} \cdot 300}{6 \text{ mA}} = 75 \text{ k}\Omega$$

If the alarm condition is true, the ALARM output goes HIGH (CMOS level). This signal could be used, for example, to disable the laser driver by driving the ALS input (a latch is needed in between to prevent oscillation).

Loop mode (TZA3041BHL only)

In loop mode, the total system application can be tested. It allows for uninhibited optical transmission through the fibre front end (from the photodiode through the transimpedance stage and the data and clock recovery unit, to the laser driver and via the laser back to the fibre). It should be noted that the optical receiver used in conjunction with the TZA3041BHL must have a loop mode output in order to complete the test loop.

A HIGH on pin ENL selects loop mode. By default ENL is pulled LOW by a 25 kΩ pull-down resistor.

Power supply connections

Three separate supply domains (labelled V_{CC(B)}, V_{CC(G)} and V_{CC(R)}) are used to provide isolation between the high-current outputs, the PECL/CML input and the monitor photodiode current input. The three domains should be individually filtered before being connected to a central V_{CC} (see Fig.6). The supply levels should be equal and in accordance with the values specified in Chapter "Characteristics". To maximize power supply isolation, the MPD cathode on the laser should be connected to V_{CC(G)}, and the laser diode anode to V_{CC(B)}. The inverted laser driver modulation output LAQ is generally not used. To properly balance the output stage, an equalization network with an impedance comparable to the laser is connected to LAQ. This network is referenced to V_{CC(B)}.

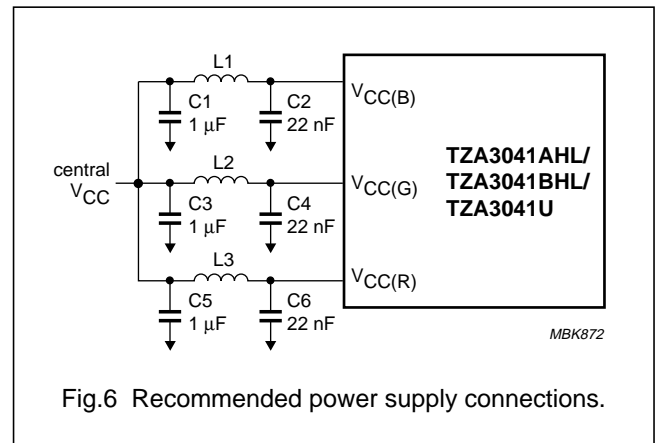


Fig.6 Recommended power supply connections.

Grounding the TZA3041U naked die

In addition to the separate V_{CC} domains, the TZA3041U naked die contains three corresponding ground domains. Isolation between the GND domains is limited due to the finite substrate conductance. Although elaborate tests have still to be done, the following grounding strategy is recommended for optimal performance.

Mount the die on a, preferably large and highly conductive, grounded die pad. All GND pads have to be bonded down to the die pad. The external ground is thus optimally combined with the die ground, thereby avoiding ground bouncing problems.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
|-----------|---|------|----------------|------|
| V_{CC} | supply voltage | -0.5 | +6 | V |
| V_n | DC voltage | | | |
| | pin 2: MONIN | 1.3 | $V_{CC} + 0.5$ | V |
| | pins 4 and 5: TONE and TZERO | -0.5 | $V_{CC} + 0.5$ | V |
| | pin 6: BGAP | -0.5 | +3.2 | V |
| | pin 15: BIAS | -0.5 | $V_{CC} + 0.5$ | V |
| | pins 12 and 13: LAQ and LA | 1.3 | $V_{CC} + 0.5$ | V |
| | pins 18 and 21: ALARMHI and ALARMLO (TZA3041AHL) | -0.5 | $V_{CC} + 0.5$ | V |
| | pins 22 and 23: ONE and ZERO | -0.5 | $V_{CC} + 0.5$ | V |
| | pins 19 and 20: data pins DLOOP and DLOOPQ (TZA3041BHL) | -0.5 | $V_{CC} + 0.5$ | V |
| | pins 28 and 29: data pins DIN and DINQ | -0.5 | $V_{CC} + 0.5$ | V |
| | pin 26: CMOS pin ALARM (TZA3041AHL) | -0.5 | $V_{CC} + 0.5$ | V |
| | pin 26: CMOS pin ENL (TZA3041BHL) | -0.5 | $V_{CC} + 0.5$ | V |
| | pin 31: CMOS pin ALS | -0.5 | $V_{CC} + 0.5$ | V |
| I_n | DC input current | | | |
| | pin 2: MONIN | 0 | 10 | mA |
| | pins 4 and 5: TONE and TZERO | -10 | +10 | mA |
| | pin 6: BGAP | -2.0 | +2.5 | mA |
| | pin 15: BIAS | 0 | 200 | mA |
| | pins 12 and 13: LAQ and LA | 0 | 100 | mA |
| | pins 18 and 21: ALARMHI and ALARMLO (TZA3041AHL) | -10 | +0.5 | mA |
| | pins 22 and 23: ONE and ZERO | -10 | +0.5 | mA |
| | pins 19 and 20: data pins DLOOP and DLOOPQ (TZA3041BHL) | -10 | +10 | mA |
| | pins 28 and 29: data pins DIN and DINQ | -10 | +10 | mA |
| | pin 26: CMOS pin ALARM (TZA3041AHL) | -10 | +10 | mA |
| | pin 26: CMOS pin ENL (TZA3041BHL) | -0.5 | +0.5 | mA |
| | pin 31: CMOS pin ALS | -0.5 | +0.5 | mA |
| T_{amb} | operating ambient temperature | -40 | +85 | °C |
| T_j | junction temperature | -40 | +125 | °C |
| T_{stg} | storage temperature | -65 | +150 | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | VALUE | UNIT |
|---------------|--|-------|------|
| $R_{th(j-s)}$ | thermal resistance from junction to solder point | 15 | K/W |
| $R_{th(j-c)}$ | thermal resistance from junction to case | tbf | K/W |

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CHARACTERISTICS

$V_{CC} = 5\text{ V}$; $T_{amb} = -40\text{ to }+85\text{ }^{\circ}\text{C}$; all voltages referenced to GND.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|---|--|-------------------|--------------------|--------------------|---------------|
| Supply | | | | | | |
| V_{CC} | supply voltage | | 4.75 | 5 | 5.25 | V |
| I_{CC} | supply current | note 1 | – | 65 ⁽²⁾ | 90 ⁽³⁾ | mA |
| P_{tot} | total power dissipation | note 4 | – | 430 ⁽⁵⁾ | 810 ⁽⁶⁾ | mW |
| Data inputs: DIN and DINQ (DLOOP and DLOOPQ on TZA3041BHL) | | | | | | |
| $V_{i(p-p)}$ | input voltage (peak-to-peak value) | 50 Ω measurement system; note 7 | 100 | 250 | 800 | mV |
| V_{IO} | permitted input offset voltage | | –25 | – | +25 | mV |
| V_I | input voltage range | | $V_{CC} - 2000$ | – | $V_{CC} + 250$ | mV |
| Z_i | low frequency single-ended input impedance | | 8 | 10 | 12 | k Ω |
| CMOS inputs: ALS (ENL on TZA3041BHL) | | | | | | |
| V_{IL} | LOW-level input voltage | | – | 0.4 | 0.8 | V |
| V_{IH} | HIGH-level input voltage | | 3.0 | 4.0 | – | V |
| CMOS output: ALARM on TZA3041AHL only | | | | | | |
| V_{OL} | LOW-level output voltage | | 0 | – | 0.2 | V |
| V_{OH} | HIGH-level output voltage | | 4.8 | – | 5 | V |
| Monitor photodiode input: MONIN | | | | | | |
| $I_{i(p-p)}$ | monitor photodiode current (peak-to-peak value) | | 100 | – | 1000 | μA |
| V_I | DC input voltage | | 1.5 | 1.8 | 2.0 | V |
| C_{MPD} | monitor photodiode capacitance | | 30 ⁽⁸⁾ | – | 50 | pF |
| Control loop reference currents: ONE and ZERO | | | | | | |
| $I_{ref(ONE)}$ | optical ONE reference current | note 9 | 6 | – | 65 | μA |
| $V_{ref(ONE)}$ | optical ONE reference voltage | referenced to $V_{CC(R)}$ | –1.55 | –1.5 | –1.45 | V |
| $I_{ref(ZERO)}$ | optical ZERO reference current | note 9 | 6 | – | 65 | μA |
| $V_{ref(ZERO)}$ | optical ZERO reference voltage | referenced to $V_{CC(R)}$ | –1.55 | –1.5 | –1.45 | V |
| Control loop time constants: TONE and TZERO | | | | | | |
| V_{TONE} | TONE voltage | | 1.5 | – | 3.5 | V |
| $g_{m(TONE)}$ | TONE transconductance | note 10 | – | 50 | – | mA/V |
| V_{TZERO} | TZERO voltage | | 1.5 | – | 3.5 | V |
| $g_{m(TZERO)}$ | TZERO transconductance | note 11 | – | 80 | – | mA/V |

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| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--|--|--------------------------------|-------|------|--------------------|---------|
| Laser modulation outputs: LA and LAQ | | | | | | |
| I_{OL} | LOW-level output current | | – | – | 2 | mA |
| I_{OH} | HIGH-level output current | | 1 | – | 60 | mA |
| $I_{O(ALS)}$ | output current during ALS | | – | – | 10 | μ A |
| V_O | output voltage | | 2 | – | 5 | V |
| t_r, t_f | rise time, fall time | | – | 120 | 250 | ps |
| $J_{o(p-p)}$ | intrinsic output jitter (peak-to-peak value) | | – | – | 50 ⁽¹²⁾ | mUI |
| Bias current output: BIAS | | | | | | |
| I_O | output current | | 2 | – | 90 | mA |
| $I_{O(ALS)}$ | output current during ALS | | – | – | 10 | μ A |
| $t_{res(ALS)}$ | ALS response time | $I_{BIAS} = 90$ mA; note 13 | – | – | 1 | μ s |
| V_O | output voltage | | 1 | – | 5 | V |
| Alarm threshold inputs: ALARMHI and ALARMLO (TZA3041AHL only) | | | | | | |
| $I_{ref(ALARMLO)}$ | lower alarm threshold reference current | note 14 | 6 | – | 65 | μ A |
| $V_{ref(ALARMLO)}$ | optical ALARMLO reference voltage | referenced to $V_{CC(R)}$ | –1.55 | –1.5 | –1.45 | V |
| $I_{ref(ALARMHI)}$ | higher alarm threshold reference current | note 14 | 6 | – | 65 | μ A |
| $V_{ref(ALARMHI)}$ | optical ALARMHI reference voltage | referenced to $V_{CC(R)}$ | –1.55 | –1.5 | –1.45 | V |

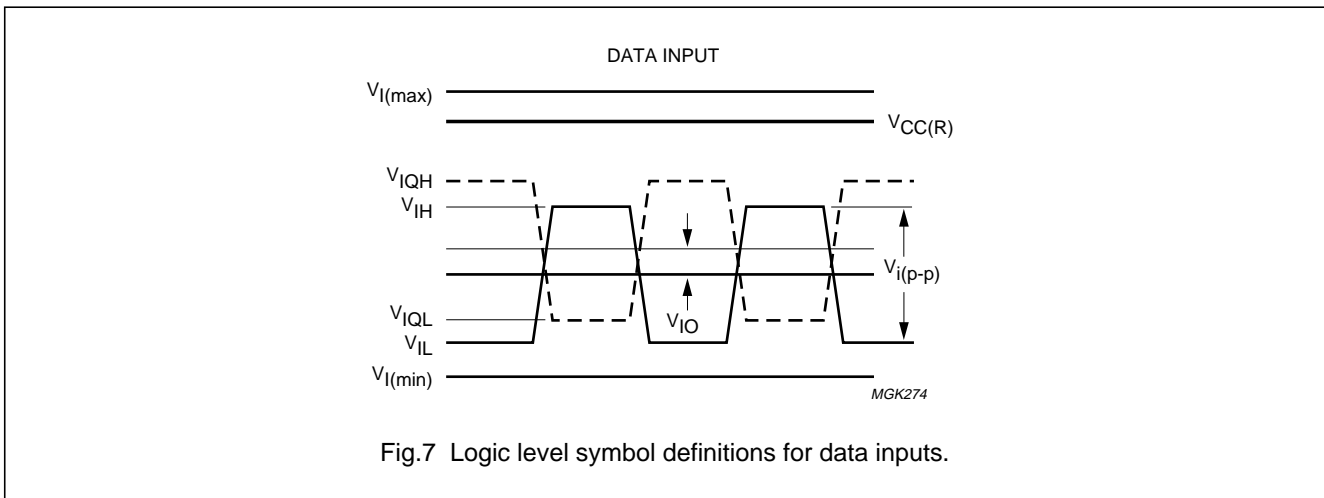
Notes

- I_{CC} does not include modulation and bias current through pins LA, LAQ and BIAS.
- Typical value for I_{CC} refers to, but does not include, $I_{MOD} = 30$ mA and $I_{BIAS} = 45$ mA.
- The maximum value of I_{CC} refers to, but does not include, $I_{MOD} = 60$ mA and $I_{BIAS} = 90$ mA.
- P_{tot} includes modulation and bias current through pins LA, LAQ and BIAS.
- The typical power dissipation is the on-chip dissipation with $I_{MOD} = 30$ mA and $V_{LA/LAQ} = 2$ V, $I_{BIAS} = 45$ mA and $V_{BIAS} = 1$ V and typical process parameters.
- The maximum power dissipation is the on-chip dissipation with $I_{MOD} = 60$ mA and $V_{LA/LAQ} = 2$ V, $I_{BIAS} = 90$ mA and $V_{BIAS} = 1$ V and worst case process parameters.
- Measured single-ended.
- A minimum value of capacitance on pin MONIN is required to prevent instability.
- The reference currents can be set by a resistor between V_{CC} and pin ONE or ZERO. The corresponding ZERO level MPD current range is from 24 to 260 μ A. The ONE level MPD current range is from 96 to 1040 μ A. See Section "Automatic laser control" for a detailed discussion.
- The specified transconductance is the ratio of modulation current at LA and LAQ to voltage at pin TONE, under small signal conditions.
- The specified transconductance is the ratio of biasing current at BIAS to voltage at pin TZERO, under small signal conditions.

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- 12. Measured according to IEEE 802.3z and ANSI X3.230 The electrically generated (current) jitter is assumed to be less than 50% of the optical output jitter.
- 13. The ALS response time is defined as the delay between the onset of the ALS ramp (10% of the HIGH logic level) and the extinction of the bias current (10% of the original value).
- 14. The reference currents can be set by using a resistor between $V_{CC(R)}$ and pin ALARMLO or ALARMHI.
The corresponding range of low-bias thresholds is between 1.8 and 19.5 mA. The high-bias threshold range is from 9 to 97.5 mA. See Section "Bias alarm (TZA3041AHL only)" for detailed information.

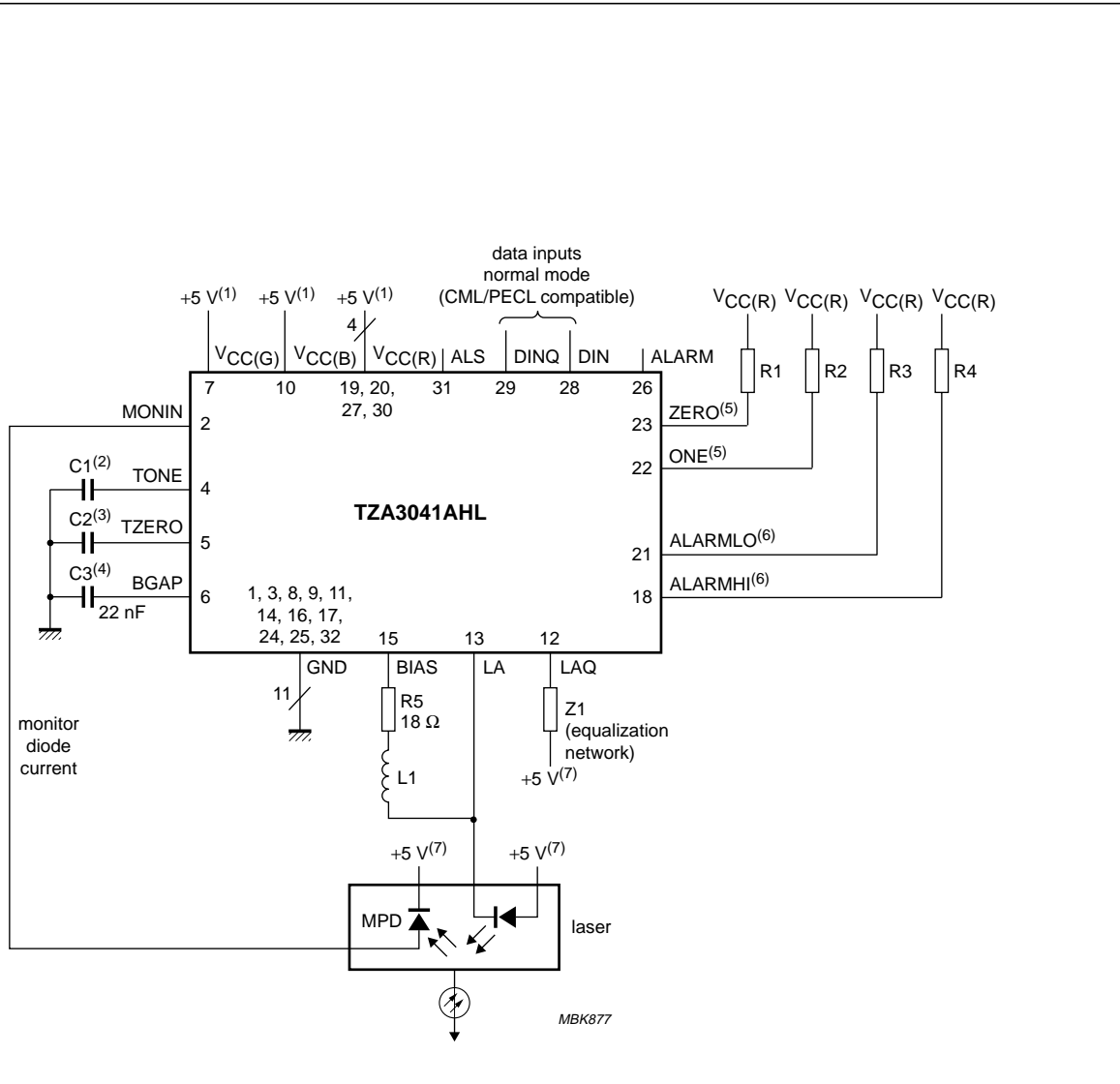


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TZA3041U

APPLICATION INFORMATION

TZA3041AHL



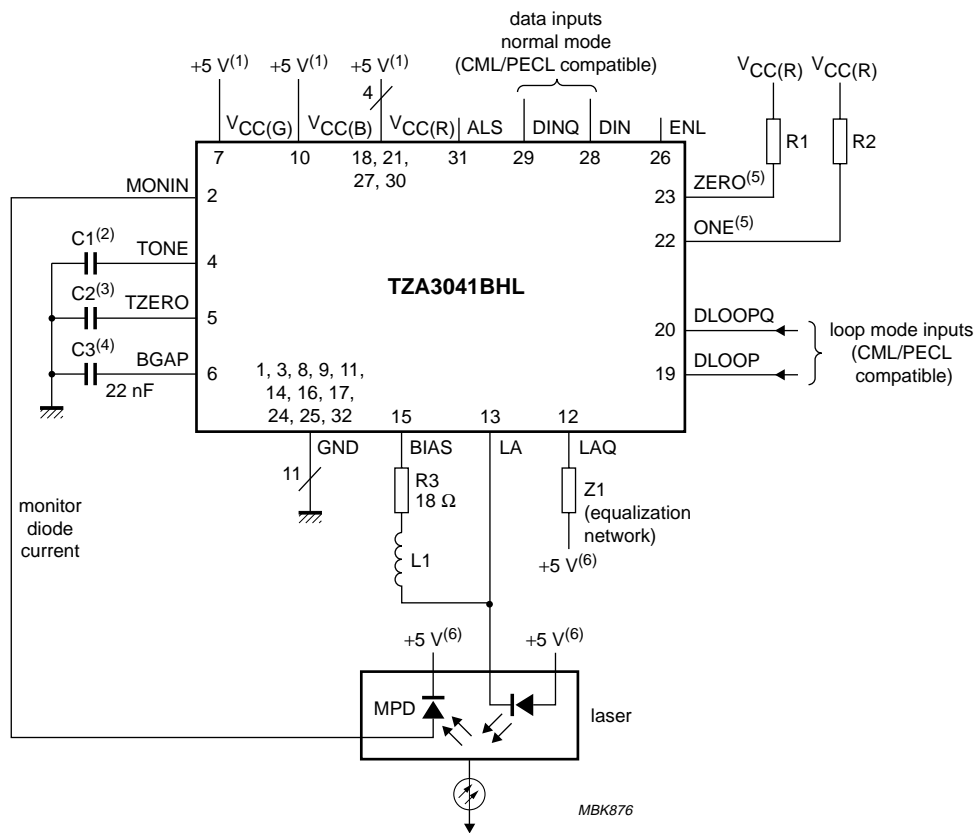
- (1) A filter should be connected between the pin and the 5 V supply; see Section "Power supply connections".
- (2) C1 enhances modulation control loop time constant (optional).
- (3) C2 enhances bias control loop time constant (optional).
- (4) Band gap noise filter.
- (5) Optical ZERO and ONE reference currents are set using resistors to $V_{CC(R)}$; see Section "Automatic laser control".
- (6) Minimum and maximum bias currents are set using resistors to $V_{CC(R)}$; see Section "Bias alarm (TZA3041AHL only)".
- (7) See Section "Power supply connections".

Fig.8 Application diagram showing the TZA3041AHL configured for 1.2 Gbits/s (Gigabit Ethernet/Fibre Channel).

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- (1) A filter should be connected between the pin and the 5 V supply; see Section "Power supply connections".
- (2) C1 enhances modulation control loop time constant (optional).
- (3) C2 enhances bias control loop time constant (optional).
- (4) Band gap noise filter.
- (5) Optical ZERO and ONE reference currents are set using resistors to V_{CC}; see Section "Automatic laser control".
- (6) See Section "Power supply connections".

Fig.9 Application diagram showing the TZA3041BHL configured for 1.2 Gbits/s (Gigabit Ethernet/Fibre Channel).

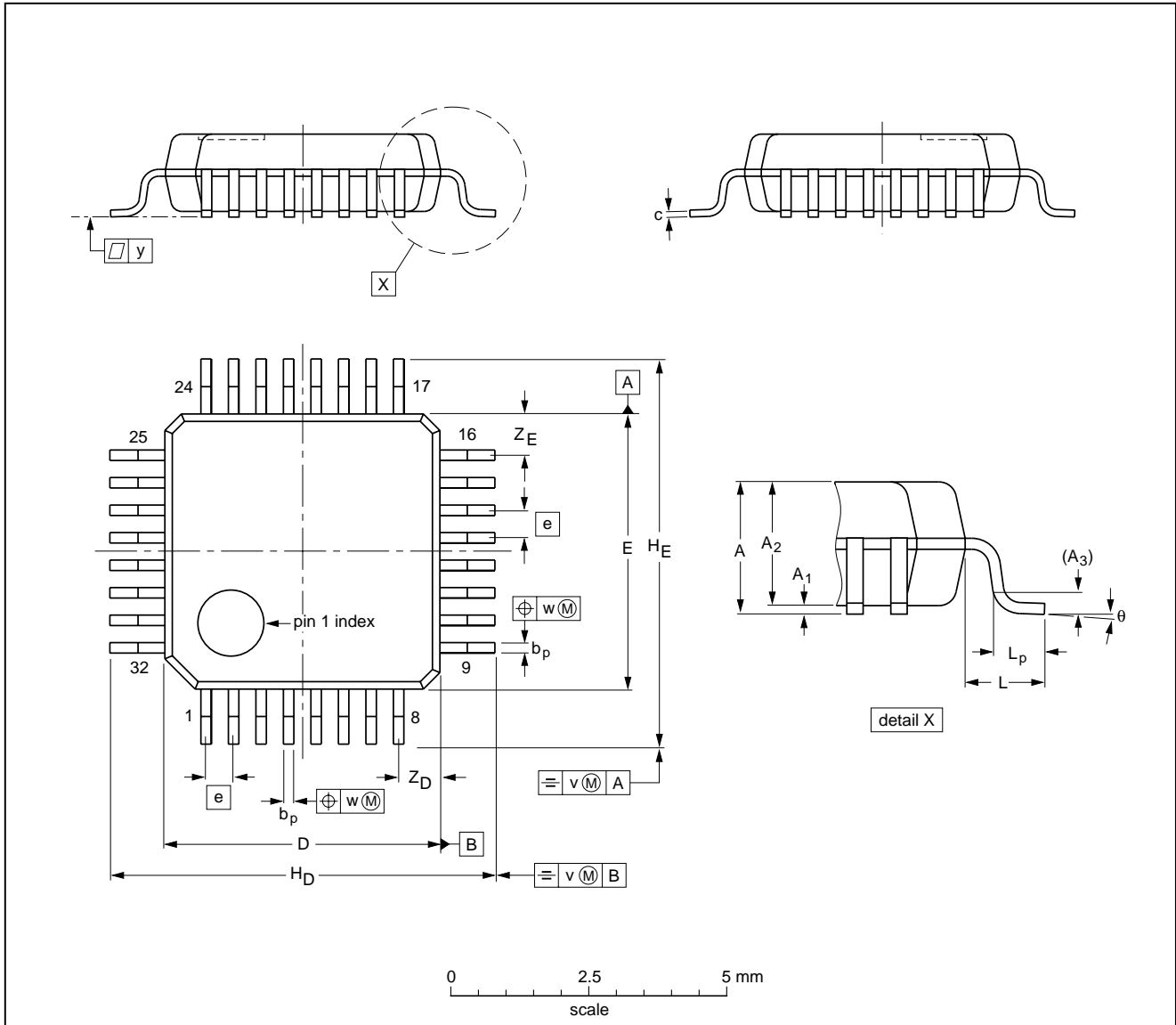
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PACKAGE OUTLINE

LQFP32: plastic low profile quad flat package; 32 leads; body 5 x 5 x 1.4 mm

SOT401-1



DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | A ₁ | A ₂ | A ₃ | b _p | c | D ⁽¹⁾ | E ⁽¹⁾ | e | H _D | H _E | L | L _p | v | w | y | Z _D ⁽¹⁾ | Z _E ⁽¹⁾ | θ |
|------|--------|----------------|----------------|----------------|----------------|--------------|------------------|------------------|-----|----------------|----------------|-----|----------------|-----|------|-----|-------------------------------|-------------------------------|----------|
| mm | 1.60 | 0.15 0.05 | 1.5 1.3 | 0.25 | 0.27 0.17 | 0.18 0.12 | 5.1 4.9 | 5.1 4.9 | 0.5 | 7.15 6.85 | 7.15 6.85 | 1.0 | 0.75 0.45 | 0.2 | 0.12 | 0.1 | 0.95 0.55 | 0.95 0.55 | 7° 0° |

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-------|------|---------------------|----------------------|
| | IEC | JEDEC | EIAJ | | |
| SOT401-1 | | | | | 95-12-19 97-08-04 |

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SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (order code 9398 652 90011).

Reflow soldering

Reflow soldering techniques are suitable for all LQFP packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 50 and 300 seconds depending on heating method. Typical reflow peak temperatures range from 215 to 250 °C.

Wave soldering

Wave soldering is **not** recommended for LQFP packages. This is because of the likelihood of solder bridging due to closely-spaced leads and the possibility of incomplete solder penetration in multi-lead devices.

If wave soldering cannot be avoided, for LQFP packages with a pitch (e) larger than 0.5 mm, the following conditions must be observed:

- **A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.**
- **The footprint must be at an angle of 45° to the board direction and must incorporate solder thieves downstream and at the side corners.**

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Repairing soldered joints

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

| |
|---|
| CAUTION |
| Wave soldering is NOT applicable for all LQFP packages with a pitch (e) equal or less than 0.5 mm. |

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laser drivers**

**TZA3041AHL; TZA3041BHL;
TZA3041U**

DEFINITIONS

| | |
|---|---|
| Data sheet status | |
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |

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